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Inclosure Material:

Metal

Overall Length:

Between 0.325 inches and 0.460 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.667 inches and 0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

180.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

5.00 amperes source cutoff current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Test Data Document:

82577-928302 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 wire hook and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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